

SK22 THRU SK210

Surface Mount Schottky Barrier Rectifiers

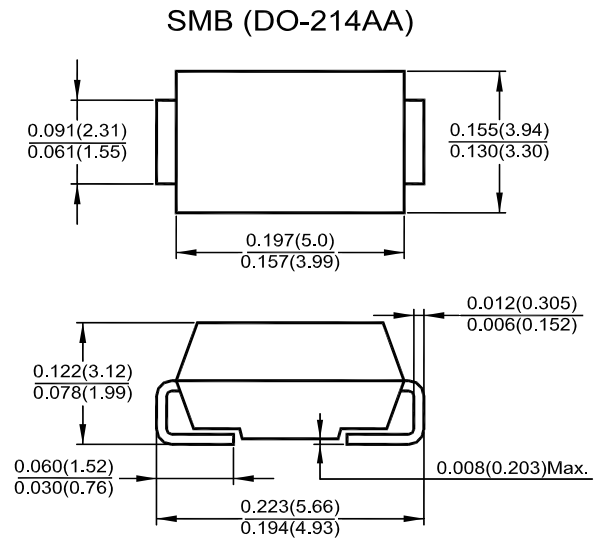
Reverse Voltage - 20 to 100 V
Forward Current - 2 A

Features

- The plastic package has Underwriters Laboratory Flammability Classification 94V-0
- Metal silicon junction, majority carrier conduction
- Built-in strain relief, ideal for automated placement
- For surface mounted applications
- Low power loss, high efficiency
- High forward surge current capability
- High temperature soldering guaranteed: 250°C/10 seconds at terminals

Mechanical Data

- **Case:** JEDEC SMB (DO-214AA) molded plastic body
- **Terminals:** solder plated, solderable per MIL-STD-750, Method 2026
- **Polarity:** color band denotes cathode end
- **Mounting position:** Any



Dimensions in inches and (millimeters)

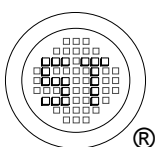
Absolute Maximum Ratings and Characteristics

Ratings at 25 °C ambient temperature unless otherwise specified. Single phase, half wave 60 Hz, resistive or inductive load; For capacitive load current derate by 20%.

Parameter	Symbols	SK22	SK23	SK24	SK25	SK26	SK28	SK210	Unit
Maximum Repetitive Peak Reverse Voltage	V_{RRM}	20	30	40	50	60	80	100	V
Maximum RMS Voltage	V_{RMS}	14	21	28	35	42	56	70	V
Maximum DC Blocking Voltage	V_{DC}	20	30	40	50	60	80	100	V
Maximum Average Forward Rectified Current	$I_{F(AV)}$	2.0							A
Peak Forward Surge Current 8.3 ms Single Half Sine-wave Superimposed on Rated Load (JEDEC Method)	I_{FSM}	50							A
Maximum Instantaneous Forward Voltage at 2 A	V_F	0.55		0.70		0.85		V	
Maximum DC Reverse Current at Rated DC Blocking Voltage	I_R	20		10		10		mA	
Typical Junction Capacitance ¹⁾	C_J	220		180		180		pF	
Typical Thermal Resistance ²⁾	$R_{\theta JA}$	75							°C/W
Operating Junction Temperature Range	T_J	- 65 to + 125			- 65 to + 150			°C	
Storage Temperature Range	T_{stg}	- 65 to + 150							°C

¹⁾ Measured at 1 MHz and applied reverse voltage of 4 V.

²⁾ P.C.B. mounted with 0.2 X 0.2" (5 X 5 mm) copper pad areas.



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FIG.1-FORWARD CURRENT DERATING CURVE

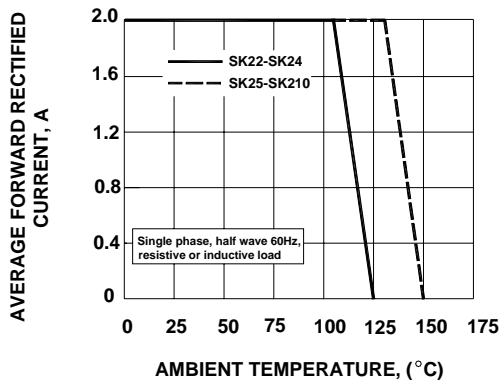


Fig.2- MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

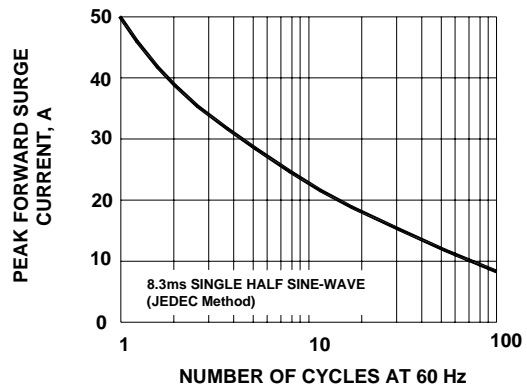


Fig.3-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

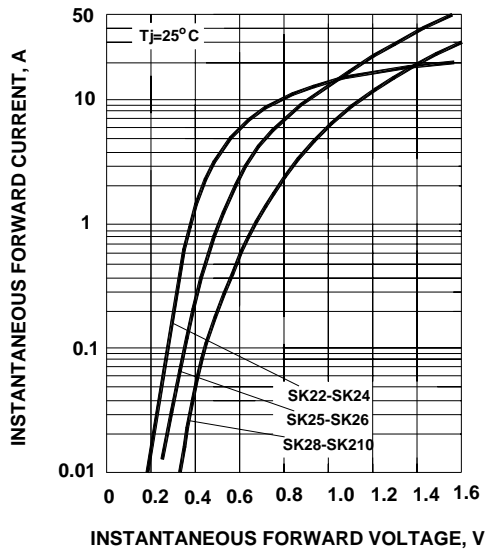


Fig.4- TYPICAL REVERSE CHARACTERISTICS

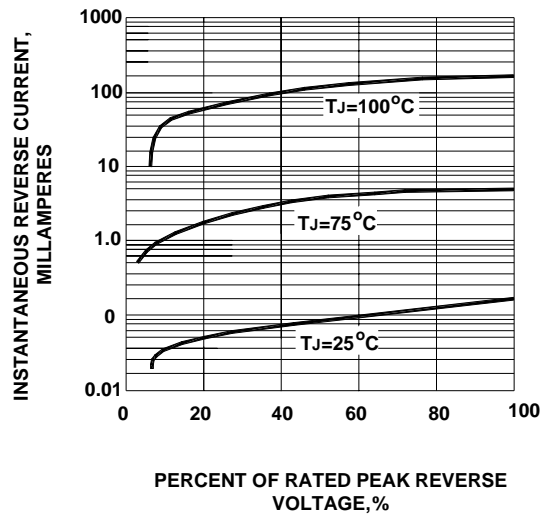


Fig.5- TYPICAL JUNCTION CAPACITANCE

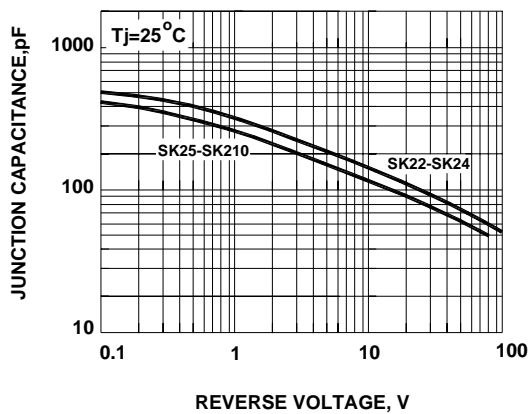
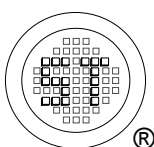
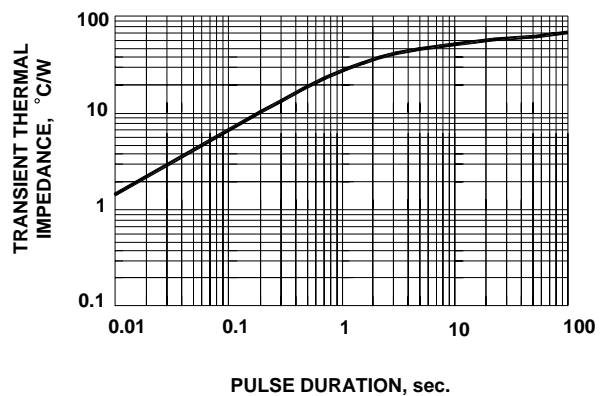


Fig.6- TYPICAL TRANSIENT THERMAL IMPEDANCE



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